	Hits	Search Text	DBs
23	1	(((cell or memory or array or Rmemo) near9 (trench$3 or STI)) same (larger or deeper or steeper or deep or steep) same (pad near9 nitride) same etch$4 same ((Rperiph$6 or periph$5) near9 (trench$3 or STI))) and gate and source and drain and ((memory or array or cell or Rmemo) same (shallow$4 or narrow$4) same etch$4 same (pad near9 nitride) same ((dop$4 or (ion near5 implant$5) or implant$4) near9 substrate near9 surface))	US-PGPUB
24	1	(((cell or memory or array or Rmemo) near9 (trench$3 or STI)) same (larger or deeper or steeper or deep or steep) same (pad near9 nitride) same etch$4 same ((Rperiph$6 or periph$5) near9 (trench$3 or STI))) and gate and source and drain and ((memory or array or cell or Rmemo) same (shallow$4 or narrow$4) same etch$4 same ((dop$4 or (ion near5 implant$5) or implant$4) near9 substrate near9 surface))	US-PGPUB

	Hits	Search Text	DBs
25	1	(((cell or memory or array or Rmemo) near9 (trench$3 or STI)) same (larger or deeper or steeper or deep or steep) same (pad near9 nitride) same etch$4 same ((Rperiph$6 or periph$5) near9 (trench$3 or STI))) and gate and source and drain and ((memory or array or cell or Rmemo) same (shallow$4 or narrow$4) same etch$4 same (pad near9 nitride) same ((dop$4 or (ion near5 implant$5) or implant$4) near9 substrate near9 surface))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB